

Vishay General Semiconductor

HALOGEN FREE

# Surface-Mount PAR® Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



**SMB (DO-214AA)** 

#### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS						
$V_{BR}$	6.8 V to 43 V					
$V_{WM}$	5.8 V to 36.8 V					
P <sub>PPM</sub>	600 W					
I <sub>FSM</sub>	75 A					
T <sub>J</sub> max.	185 °C					
Polarity	Unidirectional					
Package	SMB (DO-214AA)					

#### TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, automotive, and telecommunication.

#### **FEATURES**

- Junction passivation optimized design passivated anisotropic rectifier technology
- T<sub>J</sub> = 185 °C capability suitable for high reliability and automotive requirement
- · Available in unidirectional polarity only
- peak pulse power capability 10/1000 µs waveform, repetitive rate (duty cycle): 0.01 %
- · Excellent clamping capability
- · Very fast response time
- · Low incremental surge resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
  - Automotive ordering code: base P/NHE3 or P/NHM3
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **MECHANICAL DATA**

Case: SMB (DO-214AA)

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3\_X - RoHS-compliant and AEC-Q101 qualified Base P/NHM3\_X - halogen-free, RoHS-compliant, and AEC-Q101 qualified

("\_X" denotes revision code e.g. A, B, ...)

Terminals: matte tin plated leads, solderable J-STD-002 and JESD 22-B102

HE3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C, unless otherwise noted)								
PARAMETER	SYMBOL	VALUE	UNIT					
Peak pulse power dissipation with a 10/1000 μs waveform (fig. 1) (1)(2)	P <sub>PPM</sub>	600	W					
Peak pulse current with a 10/1000 µs waveform (fig. 3) (1)	I <sub>PPM</sub>	See table next page	Α					
Peak forward surge current 8.3 ms single half sine-wave (2)(3)	I <sub>FSM</sub>	75	А					
Maximum instantaneous forward voltage at 50 A (2)(3)	V <sub>F</sub>	3.5	V					
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +185	°C					

#### **Notes**

- Non-repetitive current pulse, per fig. 3 and derated above  $T_A = 25$  °C per fig. 2
- (2) Mounted on 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pads at each terminal
- (3) Measured on 8.3 ms single half sine-wave, or equivalent square wave, duty cycle = 4 pulses per minute maximum

# **TPSMB6.8A thru TPSMB43A**

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C, unless otherwise noted)											
DEVICE TYPE	DEVICE MARKING CODE	BREAKDOWN VOLTAGE V <sub>BR</sub> <sup>(1)</sup> AT I <sub>T</sub> (V)		TEST CURRENT I <sub>T</sub> (mA)	STAND-OFF VOLTAGE V <sub>WM</sub> (V)	MAXIMUM REVERSE LEAKAGE AT V <sub>WM</sub> I <sub>R</sub> (µA)	MAXIMUM REVERSE LEAKAGE AT V <sub>WM</sub> T <sub>J</sub> = 150 °C	MAXIMUM PEAK PULSE SURGE CURRENT I <sub>PPM</sub> <sup>(2)</sup> (A)	MAXIMUM CLAMPING VOLTAGE AT I <sub>PPM</sub> V <sub>C</sub> (V)	TYPICAL TEMP. COEFFICIENT OF V <sub>BR</sub> (3) $\alpha$ T	
		MIN.	NOM.	MAX.			(F2 9	(μ <b>A</b> )	* 4	(-)	(%/°C)
TPSMB6.8A	KEP	6.45	6.80	7.14	10	5.8	500	1000	57.1	10.5	0.047
TPSMB7.5A	KGP	7.13	7.50	7.88	10	6.4	250	500	53.1	11.3	0.052
TPSMB8.2A	KKP	7.79	8.20	8.61	10	7.02	100	200	49.6	12.1	0.056
TPSMB9.1A	KMP	8.65	9.10	9.55	1	7.78	25	50	44.8	13.4	0.060
TPSMB10A	KPP	9.5	10.0	10.5	1	8.55	5	20	41.4	14.5	0.064
TPSMB11A	KRP	10.5	11.0	11.6	1	9.4	2	5	38.5	15.6	0.067
TPSMB12A	KTP	11.4	12.0	12.6	1	10.2	2	5	35.9	16.7	0.070
TPSMB13A	KVP	12.4	13.0	13.7	1	11.1	2	5	33	18.2	0.072
TPSMB15A	KXP	14.3	15.0	15.8	1	12.8	1	5	28.3	21.2	0.076
TPSMB16A	KZP	15.2	16.0	16.8	1	13.6	1	5	26.7	22.5	0.078
TPSMB18A	LEP	17.1	18.0	18.9	1	15.3	1	5	23.8	25.2	0.080
TPSMB20A	LGP	19	20.0	21	1	17.1	1	5	21.7	27.7	0.082
TPSMB22A	LKP	20.9	22.0	23.1	1	18.8	1	5	19.6	30.6	0.084
TPSMB24A	LMP	22.8	24.0	25.2	1	20.5	1	5	18.1	33.2	0.085
TPSMB27A	LPP	25.7	27.0	28.4	1	23.1	1	5	16	37.5	0.087
TPSMB30A	LRP	28.5	30.0	31.5	1	25.6	1	5	14.5	41.4	0.088
TPSMB33A	LTP	31.4	33.0	34.7	1	28.2	1	5	13.1	45.7	0.089
TPSMB36A	LVP	34.2	36.0	37.8	1	30.8	1	5	12	49.9	0.090
TPSMB39A	LXP	37.1	39.0	41.0	1	33.3	1	5	11.1	53.9	0.091
TPSMB43A	LZP	40.9	43.0	45.2	1	36.8	1	5	10.1	59.3	0.092

#### Notes

<sup>(4)</sup> All terms and symbols are consistent with ANSI/IEEE C62.35

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TPSMB6.8AHE3_A/H (1)	0.096	Н	750	7" diameter plastic tape and reel			
TPSMB6.8AHE3_A/I (1)	0.096	1	3200	13" diameter plastic tape and reel			
TPSMB6.8AHM3_A/H (1)	0.096	Н	750	7" diameter plastic tape and reel			
TPSMB6.8AHM3_A/I (1)	0.096	I	3200	13" diameter plastic tape and reel			

#### Note

(1) AEC-Q101 qualified

 $<sup>^{(1)}</sup>$  V<sub>BR</sub> measured after I<sub>T</sub> applied for 300  $\mu$ s, I<sub>T</sub> = square wave pulse or equivalent

<sup>(2)</sup> Surge current waveform per fig. 3 and derated per fig. 2

<sup>(3)</sup> To calculate  $V_{BR}$  vs. junction temperature, use the following formula:  $V_{BR}$  at  $T_J = V_{BR}$  at 25 °C x (1 +  $\alpha$ T x ( $T_J$  - 25))

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## **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C, unless otherwise noted)

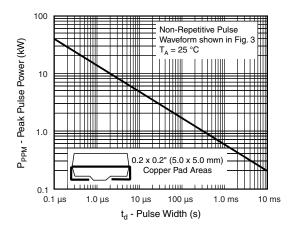


Fig. 1 - Peak Pulse Power Rating Curve

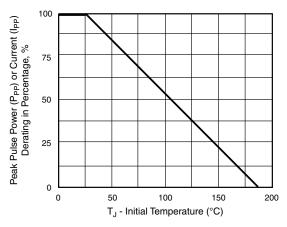


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature

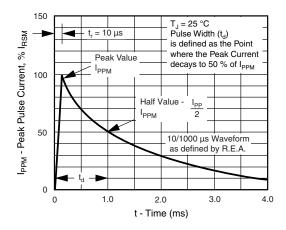


Fig. 3 - Pulse Waveform

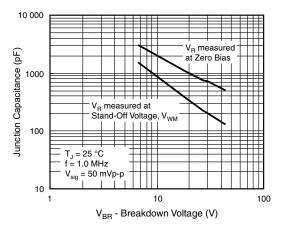


Fig. 4 - Typical Junction Capacitance

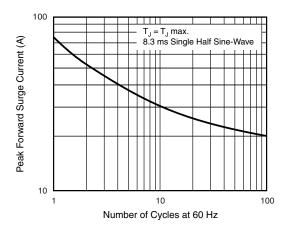


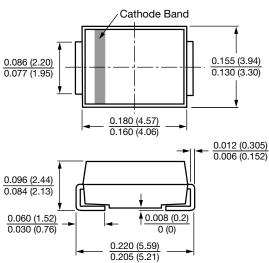
Fig. 5 - Maximum Non-Repetitive/Peak Forward Surge Current



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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

## SMB (DO-214AA)



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→ 0.220 (5.59) REF. |



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